

NWP2081T

Half-bridge driver IC

Rev. 1 — 3 September 2013

Product data sheet

1. General description

The NWP2081T is a high-voltage monolithic integrated circuit made using the latch-up free Silicon-On-Insulator (SOI) process. The circuit is designed for driving MOSFETs in a half-bridge configuration.

2. Features and benefits

- Latch-up free and robust half-bridge driver
- Output driver capability: $I_{O(sink)} = 400\text{ mA}$ and $I_{O(source)} = 200\text{ mA}$
- Maximum frequency 800 kHz
- Outputs in phase with CLK input
- Adjustable dead-time
- Low active shutdown input

3. Applications

- Driver (via external MOSFETs) for any kind of load in a half-bridge configuration

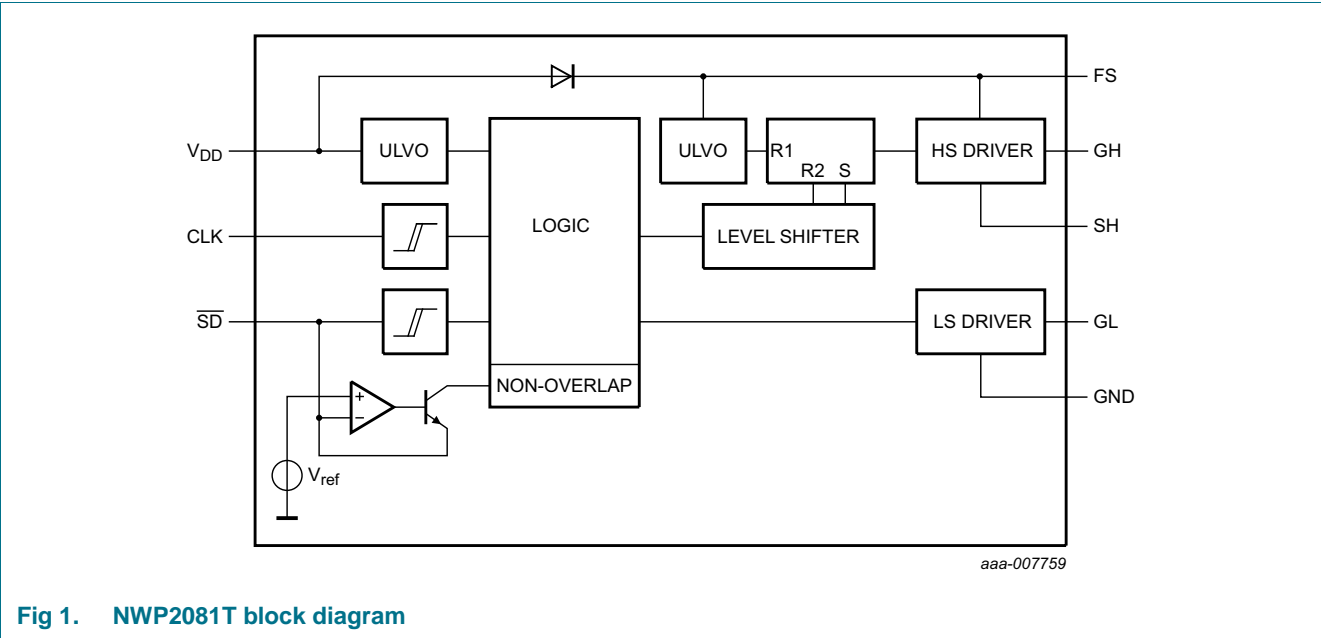
4. Ordering information

Table 1. Ordering information

| Type number | Package | | |
|-------------|---------|----------------------------------------|---------|
| | Name | Description | Version |
| NWP2081T | SO8 | plastic small outline package; 8 leads | SOT96-1 |



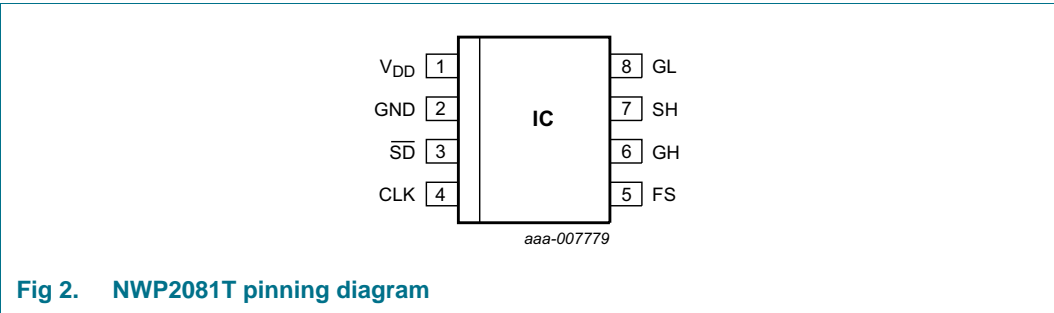
5. Block diagram



Refer to [Figure 4](#) for detailed information on the required application components.

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description NWP2081T

| Symbol | NWP2081T (SO8) | Description |
|-----------------|----------------|---------------------------------------------------------------|
| V_{DD} | 1 | IC supply |
| GND | 2 | IC ground and low-side driver return |
| \overline{SD} | 3 | low active analog shutdown input and non-overlap time setting |
| CLK | 4 | clock logic input |
| FS | 5 | floating supply voltage |

Table 2. Pin description NWP2081T ...continued

| Symbol | NWP2081T (SO8) | Description |
|--------|----------------|-------------------------|
| GH | 6 | high-side MOSFET gate |
| SH | 7 | high-side MOSFET source |
| GL | 8 | low-side MOSFET gate |

7. Functional description

7.1 Start-up state

The IC enters the start-up state when the supply voltage on pin V_{DD} increases. In the start-up state, the high-side power transistor is non-conducting and the low-side power transistor is switched on. The internal circuit is reset and the capacitor on the bootstrap pin FS is charged. The start-up state is defined until the value of V_{DD} = the $V_{DD(start)}$ value. After which the IC switches to the oscillation state.

The circuit enters the start-up state again when the voltage on pin $V_{DD} < V_{DD(stop)}$.

7.2 NWP2081T oscillation state

In the oscillation state, the output voltage of the GL and GH drivers depend on the logical signals CLK and \overline{SD} (see [Table 3](#)).

Table 3. NWP2081T logic table

| State | CLK | \overline{SD} | GH | GL |
|-------------|-----|-----------------|------|------|
| start-up | - | - | LOW | HIGH |
| oscillation | 0 | 1 | LOW | HIGH |
| oscillation | 1 | 1 | HIGH | LOW |
| oscillation | 0 | 0 | LOW | LOW |
| oscillation | 1 | 0 | LOW | LOW |

7.3 NWP2081T non-overlap time

The external resistor (R_{SD}) on pin \overline{SD} sets the non-overlap time of the NWP2081T. The relationship between this resistor value and actual dead-time is listed in [Figure 3](#).

It is essential to add a 10 nF to 100 nF decoupling capacitor across R_{SD} to ensure a noise immune dead-time system.

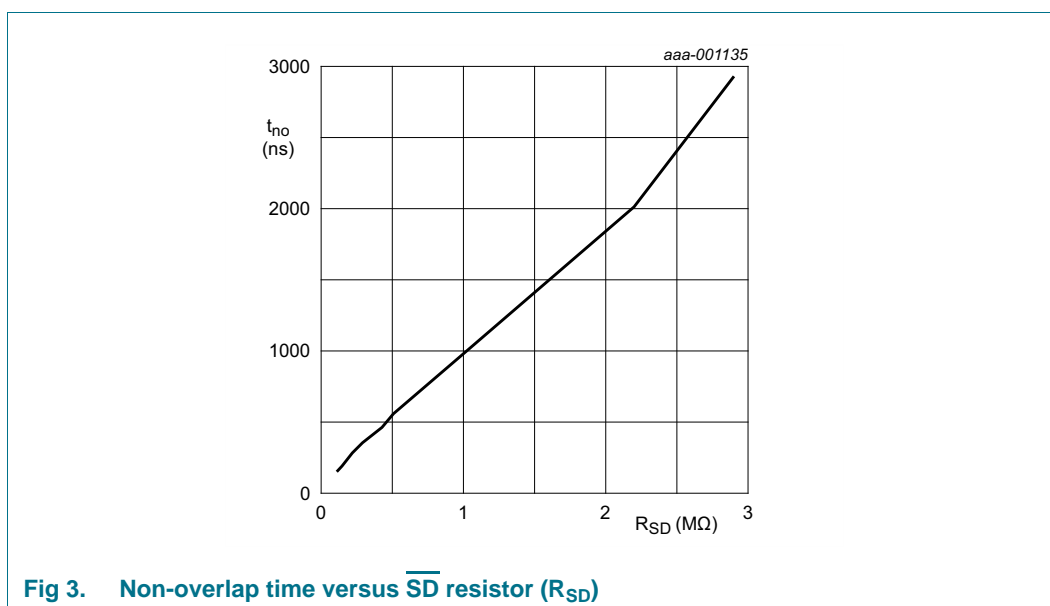


Fig 3. Non-overlap time versus \overline{SD} resistor (R_{SD})

7.4 NWP2081T shutdown protection

When the voltage at pin \overline{SD} is pulled below V_{IH} , the internal sink drivers of the pins GL and GH are immediately enabled to switch off the external power MOSFETs.

The shutdown comparator has a hysteresis of $V_{hys(SD)}$ to avoid multiple switching.

Preferably, pin \overline{SD} is pulled low via a collector of a transistor (see [Figure 4](#)) to avoid loading of this pin (Influences the non-overlap time settings) at normal operation.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|--------------------|---------------------------------------------|-------------------------------------------------------------------------|---------------------|------------------------|------|
| V _{DD} | supply voltage | nominal | 0 | 15.5 | V |
| V _{FS} | voltage on pin FS | | V _{SH} | V _{SH} + 15.5 | V |
| V _{SH} | voltage on pin SH | source high-side MOSFET | -3 | +600 | V |
| | | t < 1 μs | -14 | +600 | V |
| V _{CLK} | voltage on pin CLK | logic input for output drivers | 0 | 15.5 | V |
| V _{i(SD)} | input voltage on pin $\overline{\text{SD}}$ | logic input for output drivers and analog input for non-overlap setting | 0 | 15.5 | V |
| SR | slew rate | on pin SH; repetitive | -6 | +6 | V/ns |
| T _j | junction temperature | | -40 | +150 | °C |
| T _{amb} | ambient temperature | | -40 | +150 | °C |
| T _{stg} | storage temperature | | -55 | +150 | °C |
| V _{ESD} | electrostatic discharge voltage | human body model: | [1] | | |
| | | pins FS, GH and SH | - | 1 | kV |
| | | pins V _{DD} , $\overline{\text{SD}}$, CLK, and GL | - | 2 | kV |
| | | charge device model: | [2] | | |
| | | all pins | - | 500 | V |

[1] In accordance with the Human Body Model (HBM): equivalent to discharging a 100 pF capacitor through a 1.5 kΩ series resistor.

[2] In accordance with the Charged Device Model (CDM): equivalent to discharging the IC up to 1 kV and the subsequent discharging of each pin down to 0 V over a 1 Ω resistor.

9. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Typ | Unit |
|----------------------|---------------------------------------------|-------------|-------------------------|------|
| SO8 | | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | [1] 160 | K/W |

[1] In accordance with IEC 60747-1.

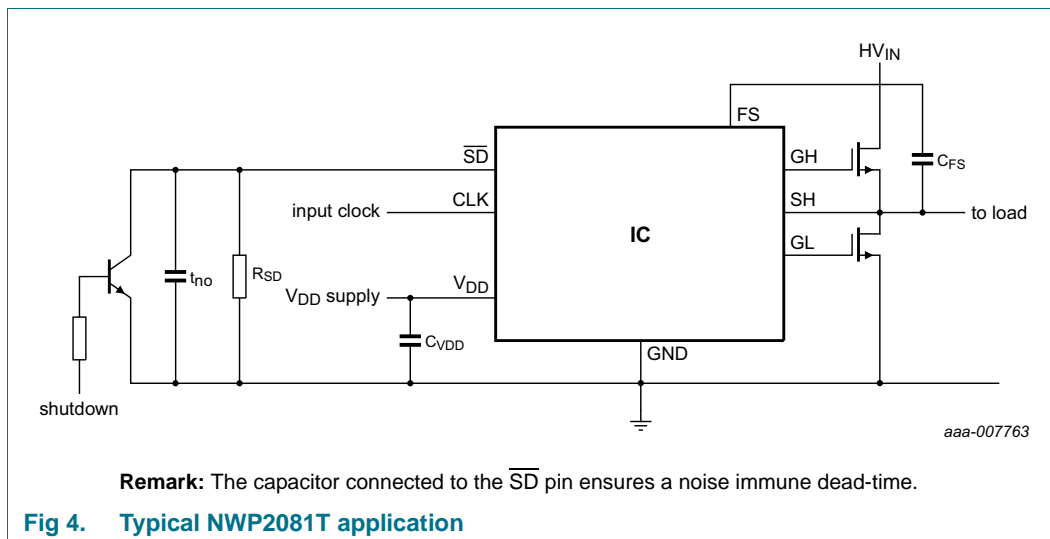
10. Characteristics

Table 6. Characteristics

$T_j = 25\text{ }^{\circ}\text{C}$; all voltages are measured with respect to SGND; $V_{DD} = 12.8\text{ V}$; positive currents flow into the IC.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------------|--------------------------------|--------------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| High-voltage supply | | | | | | |
| I _{leak} | leakage current | FS = GH = SH = 600 V | - | - | 10 | μA |
| Start-up state | | | | | | |
| I _{VDD} | current on pin V _{DD} | | 420 | 520 | 620 | μA |
| V _{DD(start)} | start supply voltage | | 9 | 10 | 11 | V |
| V _{DD(stop)} | stop supply voltage | | 8 | 8.5 | 9 | V |
| V _{DD(hys)} | hysteresis of supply voltage | start-to-stop | 1 | 1.5 | 2 | V |
| Pin CLK input | | | | | | |
| V _{IH} | HIGH-level input voltage | | 2.7 | - | - | V |
| V _{IL} | LOW-level input voltage | | - | - | 0.8 | V |
| I _{I(CLK)} | input current on pin CLK | | - | 0 | 1 | μA |
| Pin SD input | | | | | | |
| V _{IH} | HIGH-level input voltage | to activate shutdown | 1.6 | 2.2 | 2.8 | V |
| V _{hys(SD)} | hysteresis voltage on pin SD | | - | 400 | - | mV |
| t _{no} | non-overlap time | R _{SD} = 100 kΩ; typical minimum | - | 140 | - | ns |
| | | R _{SD} = 3 MΩ; typical maximum | - | 2.4 | - | μs |
| Gate drivers | | | | | | |
| I _{O(source)} | output source current | V _{FS} = V _{VDD} = 12 V; V _{SH} = 0 V; V _{GH} = V _{GL} = 8 V | - | 200 | - | mA |
| I _{O(sink)} | output sink current | V _{FS} = V _{VDD} = 12 V; V _{SH} = 0 V; V _{GH} = V _{GL} = 4 V | - | 400 | - | mA |
| V _{d(bs)} | bootstrap diode voltage | I _{d(bs)} = 20 mA | - | 2.3 | - | V |
| V _{UVLO} | undervoltage lockout voltage | reset | 3.6 | 4.2 | 4.8 | V |
| I _{FS} | current on pin FS | V _{FS} = V _{VDD} = 12 V; V _{SH} = 0 V | 27 | 32 | 37 | μA |
| f _{max} | maximum frequency | | 800 | - | - | kHz |

11. Application information



12. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1

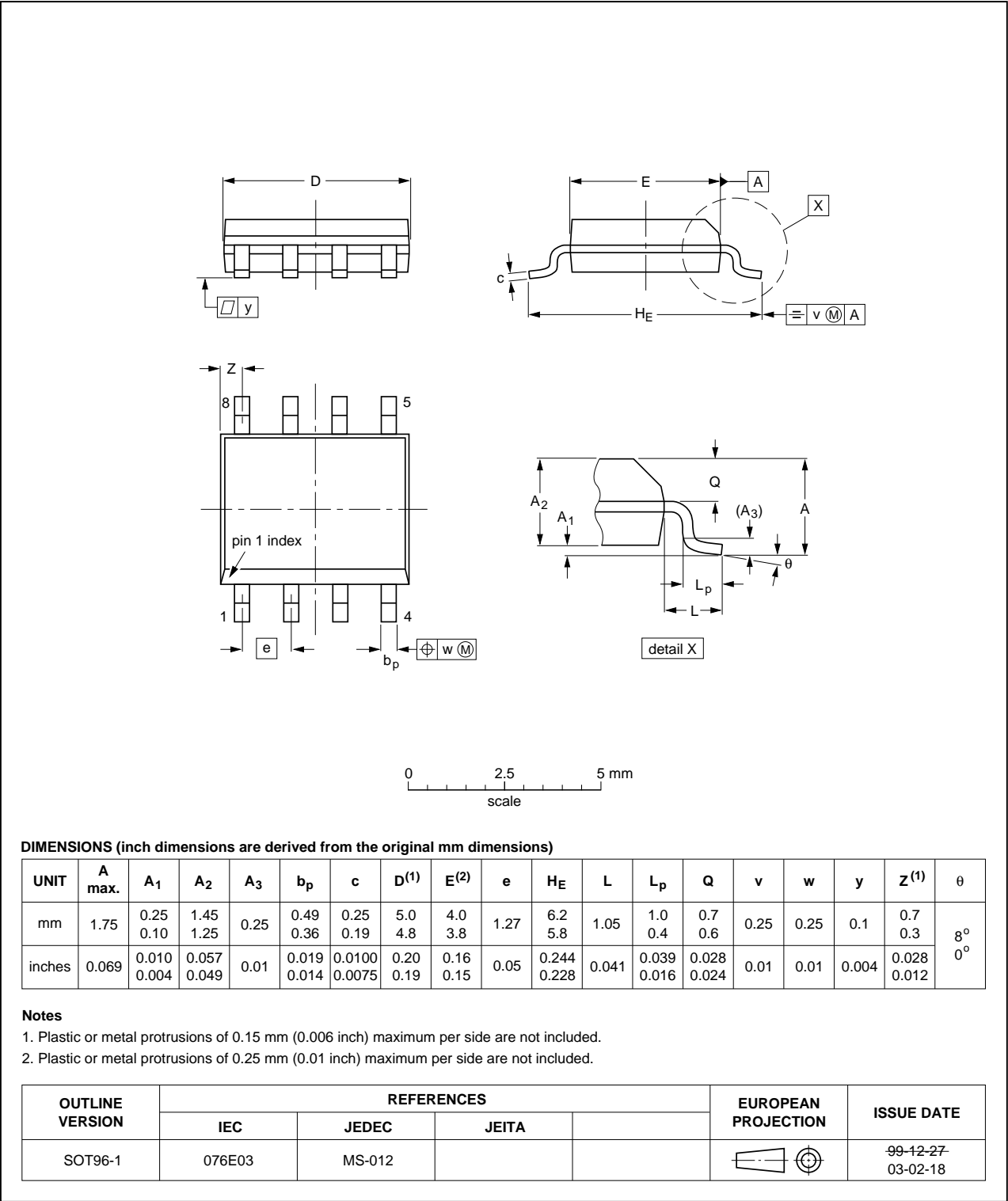


Fig 5. Package outline SOT96-1 (SO8)

13. Revision history

Table 7. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|--------------|--------------|--------------------|---------------|------------|
| NWP2081T v.1 | 20130903 | Product data sheet | - | - |

14. Legal information

14.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
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